Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
11	208	(polysilicon adj gate) and (source and drain) and (silicide adj (layer or film)) and (silicid\$4 or salicid\$4) and @ad<="20040326" and (cobalt adj silicide) and (nickel adj silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/03 10:20
L15	2585	(gate or (gate adj electrode)) near silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	·ON	2006/05/03 10:19
L16	2306	(gate) near silicide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/03 10:19
L17	26	(polysilicon adj gate) and (source and drain) and (silicide adj (layer or film)) and ((silicid\$4 or salicid\$4) adj (polysilicon adj gate)) and @ad<="20040326" and (cobalt adj silicide) and (nickel adj silicide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/03 10:21
L18	165	(polysilicon adj gate) and (source and drain) and (silicide adj (layer or film)) and ((silicid\$4 or salicid\$4) adj (polysilicon adj gate)) and @ad<="20040326"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/03 10:21
L19	.	("5196357" "5688704" "5731239" "5856225" "5966597" "6060387" "6093628" "6096643").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/05/03 10:54
S6	0	(polysilicon adj gate adj electrode) with (protect\$ adj (layer or film)) with (wet adj etch\$6)	US-PGPUB; USPAT	OR	ON	2005/11/17 13:04
S7	114	(polysilicon adj gate adj electrode) and (protect\$ adj (layer or film)) and (wet adj etch\$6)	US-PGPUB; USPAT	OR	ON	2005/06/07 08:54
S8	2	(polysilicon adj gate adj electrode) same (protect\$ adj (layer or film)) same (wet adj etch\$6)	US-PGPUB; USPAT	OR	ON	2005/06/07 09:10

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S9	0	438/257,583.ccls. and(polysilicon adj gate adj electrode) same (protect\$ adj (layer or film)) same (wet adj etch\$6)	US-PGPUB; USPAT	OR	ON .	2005/06/07 09:10
S10	0	438/257,583.ccls. and (polysilicon adj gate adj electrode) same (protect\$ adj (layer or film)) same (wet adj etch\$6)	US-PGPUB; USPAT	OR	ON	2005/06/07 09:10
S11	2	438/257,583.ccls. and (polysilicon adj gate adj electrode) and (protect\$ adj (layer or film)) and (wet adj etch\$6)	US-PGPUB; USPAT	OR	ON	2005/06/07 09:10
S12	2	(polysilicon adj gate adj electrode) with (source and drain) with ((protect\$ or block\$6) adj (layer or film)) with (silicide)	US-PGPUB; USPAT	OR	ON ,	2005/06/08 10:38
S13	213	(polysilicon adj gate adj electrode) and (source and drain) and ((protect\$ or block\$6) adj (layer or film)) and (silicide)	US-PGPUB; USPAT	OR	ON	2005/06/08 10:50
S18	39	(polysilicon adj gate adj electrode) and (source and drain) and (((protect\$ or block\$6) adj (layer or film)) with (silicide))	US-PGPUB; USPAT	OR	ON	2005/06/08 10:50
S19	13	(polysilicon adj gate adj electrode) and (source and drain) and (((protect\$ or block\$6) adj (layer or film)) near (silicide))	US-PGPUB; USPAT	OR	ON	2005/06/08 10:59
S20	76	(polysilicon adj gate adj electrode) and (source and drain) and (((protect\$ or block\$6) adj (layer or film)) same (silicide))	US-PGPUB; USPAT	OR	ON	2005/06/08 10:50
S21	134	(polysilicon adj gate adj electrode) and (source and drain) and (((protect\$ or block\$6 or mask\$6) adj (layer or film)) same (silicide))	US-PGPUB; USPAT	OR	ON .	2005/06/08 10:51
S22	75	(polysilicon adj gate adj electrode) and (source and drain) and (((protect\$ or block\$6 or mask\$6) adj (layer or film)) with (silicide))	US-PGPUB; USPAT	OR	ON	2005/06/08 11:06
S23	55	(polysilicon adj gate adj electrode) and (source and drain) and (((protect\$ or block\$6 or masking) adj (layer or film)) with (silicide))	US-PGPUB; USPAT	OR.	ON	2005/06/08 11:03
S24	75	(polysilicon adj gate adj electrode) and (source and drain) and (((protect\$ or block\$6 or mask\$6) adj (layer or film)) with (silicide)) and @ad<="20040326"	US-PGPUB; USPAT	OR	ON	2005/11/17 13:35

S25	8	(("6800905") or ("6770516") or ("6768158") or ("6630388") or ("6525403") or ("6432829") or ("6642090") or ("6764884")).PN.	USPAT	OR	OFF	2005/06/08 13:33
S27	75	(polysilicon adj gate adj electrode) and (source and drain) and ((((protect\$ or block\$6 or mask\$6) adj (layer or film)) with (silicide)) with (silicid\$6)) and @ad<="20040326"	US-PGPUB; USPAT	OR	ON	2005/06/08:12:26
S28	8	((polysilicon adj gate adj electrode) same (source and drain) same ((((protect\$ or block\$6 or mask\$6) adj (layer or film)) with (silicide)) with (silicid\$6))) and @ad<="20040326"	US-PGPUB; USPAT	OR	ON	2005/06/08 12:27
S29	2	((polysilicon adj gate adj electrode) with (source and drain) with ((((protect\$ or block\$6 or mask\$6) adj (layer or film)) with (silicide)) with (silicid\$6))) and @ad<="20040326"	US-PGPUB; USPAT	OR	ON	2005/06/10 07:12
S30	75	((polysilicon adj gate adj electrode) and (source and drain) and ((((protect\$ or block\$6 or mask\$6) adj (layer or film)) with (silicide)) with (silicid\$6))) and @ad<="20040326"	US-PGPUB; USPAT	OR	ON	2005/06/08 12:27
S31	2	((polysilicon adj gate adj electrode) with (source and drain) with ((((protect\$ or block\$6 or mask\$6) adj (layer or film)) with (silicide)) with (silicid\$6 or salicid\$6))) and @ad<="20040326"	US-PGPUB; USPAT	OR	ON	2005/06/08 12:29
S32	8	((polysilicon adj gate adj electrode) same (source and drain) same ((((protect\$ or block\$6 or mask\$6) adj (layer or 'film)) with (silicide)) with (silicid\$6 or salicid\$6))) and @ad<="20040326"	US-PGPUB; USPAT	OR	ON	2005/06/08 12:29

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S33	16	(("6787854") or ("6642090") or ("6475890") or ("6472258") or ("6475869") or ("20020153587") or ("20020130354") or ("20020177263") or ("20030122186") or ("6583469") or ("6413802") or ("6300182") or ("675757038")).PN.	US-PGPUB; USPAT	OR	OFF	2005/06/08 14:05
S34	7	(("5462638") or ("5486282") or ("5796168") or ("5620611") or ("5937320") or ("6293457") or ("6468413")).PN.	US-PGPUB; USPAT	OR	OFF	2005/06/08 14:56
S94	1	("6489229").PN.	USPAT	OR	OFF	2005/06/10 07:24
S10 1	7	(("20050121748") or ("5323032") or ("5665616") or ("5599723")). PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/10 06:51
S10 3	. 2	(((polysilicon adj gate adj electrode) and (source and drain)) with (((protect\$ or block\$6 or mask\$6) adj (layer or film)) with (silicide)) with (silicid\$6 or salicid\$6)) and @ad<="20040326"	US-PGPUB; USPAT	OR	ON	2005/06/10 07:16
S10 4	15	(((polysilicon adj gate adj electrode) and (source and drain)) with ((silicid\$6 or salicid\$6) adj gate)) and @ad<="20040326"	US-PGPUB; USPAT	OR	ON	2005/06/10 07:21
S10 5	99	(438/583).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/10 07:22
S10 6	1232	(438/592):CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/10 07:23
S10 7	485	(438/649).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/10 07:23

S10 8	132	(438/651).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/06/10 07:23
S10 9	1	("6140210").PN.	USPAT	OR	OFF	2005/06/10 07:24
S11 0	1	("20050215037").PN.	US-PGPUB	OR	OFF	2005/11/03 14:34
S11 1	7113	((gate or electrode) with (silicid\$4 or salicid\$4)) and ((source and drain) with (silicide))	US-PGPUB; USPAT	OR	ON	2005/11/03 14:37
S11 2	6910	((gate) with (silicid\$4 or salicid\$4)) and ((source and drain) with (silicide))	US-PGPUB; USPAT	OR	ON	2005/11/03 14:37
S11 3	6889	((gate) with (silicid\$4 or salicid\$4)) and ((source same drain) with (silicide))	US-PGPUB; USPAT	OR	ON.	2005/11/03 14:37
S11 4	6185	((gate) with (silicid\$4 or salicid\$4)) and ((source near drain) with (silicide))	US-PGPUB; USPAT	OR	ON	2005/11/03 14:38
S11 5	4891	(((gate) with (silicid\$4 or salicid\$4)) and ((source near drain) with (silicide))) and polysilicon	US-PGPUB; USPAT	OR	ON	2005/11/03 14:41
S11 6	849	(((gate) with (silicid\$4 or salicid\$4)) and ((source near drain) with (silicide))) and (silicid\$4 adj gate)	US-PGPUB; USPAT	OR	ON	2005/11/04 08:58
S11 7	592	(((gate) with (silicid\$4 or salicid\$4)) and ((source near drain) with (silicide))) and (silicid\$4 adj gate)	USPAT	OR	ON	2005/11/04 08:32
S11 8	257	(((gate) with (silicid\$4 or salicid\$4)) and ((source near drain) with (silicide))) and (silicid\$4 adj gate)	US-PGPUB	OR	ON	2005/11/04 08:58
S12 1	6	(("6821887") or ("6555453") or ("6096609")).PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/17 13:20

S12 2	9	(polysilicon adj gate adj electrode) and (source and drain) and (((protect\$ or block\$6 or mask\$6) adj (layer or film)) with (silicide)) and @ad<="20040326" and (cobalt adj silicide) and (nickel adj silicide)	US-PGPUB; USPAT	OR	ON	2006/05/02 18:50
S12 8	4	and drain) and (((protect\$ or block\$6 or mask\$6) adj (layer or film)) near (silicide)) and (silicid\$4 or salicid\$4) and	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/05/02 18:56